

NLAS4717

4.5 Ω High Bandwidth, Dual SPDT Analog Switch

The NLAS4717 is an advanced CMOS analog switch fabricated in sub-micron silicon gate CMOS technology. The device is a dual independent Single Pole Double Throw (SPDT) switch featuring two low $R_{DS(on)}$ of 4.5 Ω at 3.0 V.

The device also features guaranteed Break-Before-Make (BBM) switching, assuring the switches never short the driver.

The NLAS4717 is available in two small size packages:

- ♦ Micro10: 3.0 x 5.0 mm
- ♦ Flip-Chip-10: 2.0 x 1.5 mm

Features

- Low $R_{DS(on)}$: 4.5 Ω @ 3.0 V
- Matching Between the Switches $\pm 0.5 \Omega$
- Wide Low Voltage Range: 1.8 V to 5.5 V
- High Bandwidth > 40 MHz
- 1.65 V to 5.5 V Operating Range
- Low Threshold Voltages on Pins 4 and 8 (CTRL Pins)
- Ultra-Low Charge Injection ≤ 6.0 pC
- Low Standby Current – $I_{CC} = 1.0$ nA (Max) @ $T_A = 25^\circ\text{C}$
- OVT* on Pins 4 and 8 (CTRL Logic Pins)
- Pb-Free Packages are Available

Typical Applications

- Cell Phones
- PDAs
- MP3s
- Digital Still Cameras

Important Information

- ESD Protection:
HBM = 2000 V, MM = 200 V
- Latchup Max Rating: 200 mA (Per JEDEC EIA/JESD78)
- Pin-to-Pin Compatible with MAX4717

*OVT

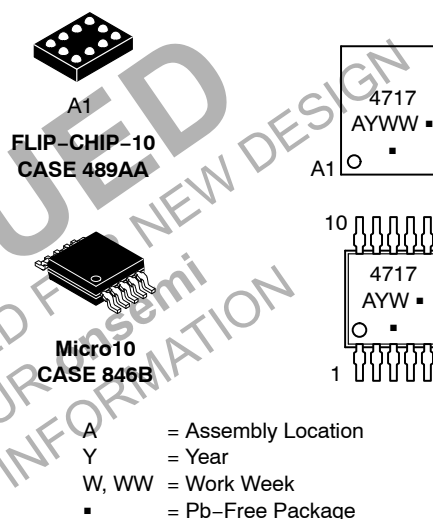
- Overvoltage Tolerance (OVT) specific pins to operate higher than normal supply voltages, with no damage to the devices or to signal integrity.



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MARKING DIAGRAMS



FUNCTION TABLE

IN ₋	NO ₋	NC ₋
0	OFF	ON
1	ON	OFF

ORDERING INFORMATION

Device	Package	Shipping†
NLAS4717FCT1	Flip-Chip-10	3000 / Tape & Reel
NLAS4717FCT1G	Flip-Chip-10 (Pb-Free)	3000 / Tape & Reel
NLAS4717MR2	Micro10	4000 / Tape & Reel
NLAS4717MR2G	Micro10 (Pb-Free)	4000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

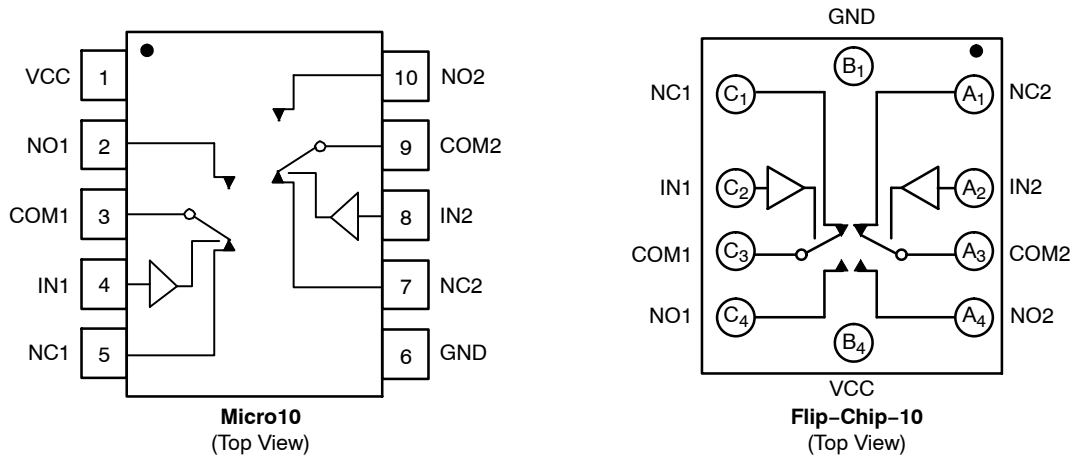


Figure 1. Device Circuit Diagrams and Pin Configurations

MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V+	Positive DC Supply Voltage	-0.5 to +7.0	V
V _{IS}	Analog Input Voltage (V _{NO} , V _{NC} , or V _{COM}) (Note 1)	-0.5 ≤ V _{IS} ≤ V _{CC} + 0.5	V
V _{IN}	Digital Select Input Voltage	-0.5 ≤ V _I ≤ +7.0	V
I _{IK}	DC Current, Into or Out of Any Pin (Continuous)	±100	mA
I _{PK}	Peak Current (10% Duty Cycle)	±200	mA

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

- Signal voltage on NC, NO, and COM exceeding V_{CC} or GND are clamped by the internal diodes. Limit forward diode current to maximum current rating.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Max	Unit
V+	DC Supply Voltage	1.8	5.5	V
V _{IN}	Digital Select Input Voltage	GND	5.5	V
V _{IS}	Analog Input Voltage (NC, NO, COM)	GND	V _{CC}	V
T _A	Operating Temperature Range	-40	+85	°C
t _r , t _f	Input Rise or Fall Time, SELECT	V _{CC} = 3.3 V ± 0.3 V V _{CC} = 5.0 V ± 0.5 V		ns/V
		0	100	
		0	20	

ANALOG SWITCH DC CHARACTERISTICS

Symbol	Parameter	Condition	V _{CC} (V)	-40°C to +85°C		Unit
				Min	Max	
V _{IH}	Input Logic High Voltage	V _{OUT} = 0.1 V I _{OUT} ≤ 20 μA	1.65 to 2.2 2.7 to 3.6 4.5 to 5.5	V _{CC} × 0.55 V _{CC} × 0.5 2.0	- - -	V
V _{IL}	Input Logic Low Voltage	V _{OUT} = -V _{CC} - 0.1 V I _{OUT} ≤ 20 μA	1.65 to 2.2 2.7 to 3.6 4.5 to 5.5	- - -	V _{CC} × 0.2 V _{CC} × 0.2 0.8	V
I _{IN}	Input Leakage Current	V _{IN} - V _{CC} or GND	5.0	-100	+100	nA
V _{CC}	Power Supply Range	All	-	1.65	5.5	V
I _{CC}	Supply Current	V _{IN} = V _{CC} or GND I _{OUT} = 0 μA	1.8 3.3 5.0	- - -	1.0 1.0 1.0	μA
V _{IS}	Analog Signal Range	Key parameter	-	0	V _{CC}	V

ANALOG SWITCH CHARACTERISTICS – Digital Section (Voltages Referenced to GND)

Symbol	Parameter	Condition	V _{CC} (V)	–40°C to +85°C			Unit
				Min	Typ	Max	
R _{ON}	ON Resistance (Note 2)	V _{CC} = 3.0 V I _{COM} = 10 mA V _{NO} or V _{NC} = V _{IH} or V _{IL}	3.0	–		4.5	Ω
		V _{CC} = 5.0 V I _{COM} = 10 mA V _{NO} or V _{NC} = V _{IH} or V _{IL}	5.0	–		3.5	
ΔR _{ON}	ON Resistance Match Between Channels (Note 2 and 3)	V _{CC} = 3.6 V I _{COM} = 10 mA V _{NO} or V _{NC} = V _{IH} or V _{IL}	3.6	–	0.1	0.4	Ω
		V _{CC} = 5.5 V I _{COM} = 10 mA V _{NO} or V _{NC} = V _{IH} or V _{IL}	5.5				
R _{FLAT[ON]}	ON Resistance Flatness (Note 4)	I _{COM} = 10 mA V _{IS} = 0 to V _{CC}	3.0	–		1.5	Ω
		I _{COM} = 10 mA V _{IS} = 0 to V _{CC}	5.5	–		1.36	
I _{NO_[OFF]} I _{NC_[OFF]}	NO_, NC_ Off-Leakage Current (Note 5)	V _{CC} = 3.6 V V _{COM} = 0.3 V or 3.3 V V _{NO} or V _{NC} = 0.3 V or 3.3 V	3.6	–1.0	0.01	+1.0	nA
		V _{CC} = 5.5 V V _{COM} = 0 V or 5.0 V V _{NO} or V _{NC} = 0 V or 5.0 V	5.5	–1.0	0.01	+1.0	
I _{COM_[ON]}	COM_ On-Leakage Current (Note 5)	V _{CC} = 3.6 V V _{COM} = 0.3 V or 3.3 V V _{NO} or V _{NC} = 0.3 V or 3.3 V	3.6	–2.0	0.01	+2.0	nA
		V _{CC} = 5.5 V V _{COM} = 0 V or 5.0 V V _{NO} or V _{NC} = 0 V or 5.0 V	5.5	–2.0	0.01	+2.0	

ANALOG SWITCH AC CHARACTERISTICS

Symbol	Parameter	Condition	V _{CC} (V)	–40°C to +85°C			Unit
				Min	Typ	Max	
t _{ON}	Turn-On Time	V _{NC_} , V _{NO_} = V _{IH} or V _{IL} R _L = 300 Ω, C _L = 35 pF V _{IN[x]} = V _{IH} or V _{IL}	1.8 to 5.5	–	–	30	nS
t _{OFF}	Turn-Off Time	V _{NC_} , V _{NO_} = V _{IH} or V _{IL} R _L = 300 Ω, C _L = 35 pF V _{IN[x]} = V _{IH} or V _{IL}	1.8 to 5.5	–	–	40	nS
t _{BBM}	Break-Before-Make Time Delay (Note 5)	V _{NC_} , V _{NO_} = 1.5 V R _L = 300 Ω, C _L = 35 pF	–	–	8.0	–	nS
t _{SKEW}	Skew (Note 5)	R _S = 39 Ω, C _L = 50 pF	–	–	0.15	2.0	nS

2. R_{ON} characterized for V_{CC} range (1.65 V to 5.5 V).
3. ΔR_{ON} = R_{ON}(MAX) – R_{ON}(MIN).
4. R_{FLAT[ON]} = R_{ON}(MAX) – R_{ON}(MIN), measured over V_{CC} range.
5. Guaranteed by design.

ANALOG SWITCH APPLICATION CHARACTERISTICS

Symbol	Parameter	Condition	V _{CC} (V)	-40°C to +85°C			Unit
				Min	Typ	Max	
Q	Charge Injection	V _{IN} = V _{CC} to GND R _{IN} = 0 Ω, C _L = 1.0 nF Q = C _L · ΔV _{OUT}	3.0 5.0		6.0 9.0		pC
VISO	Off-Isolation	f = 10 MHz V _{NO_} , V _{NC_} = 1.0 Vp-p R _L = 50 Ω, C _L = 5.0 pF	1.65 to 5.5		-50		dB
		f = 1.0 MHz V _{NO_} , V _{NC_} = 1.0 Vp-p R _L = 50 Ω, C _L = 5.0 pF			-75		
VCT	Cross-Talk	f = 10 MHz V _{NO_} , V _{NC_} = 1.0 Vp-p R _L = 50 Ω, C _L = 5.0 pF	1.65 to 5.5		-80		dB
		f = 1.0 MHz V _{NO_} , V _{NC_} = 1.0 Vp-p R _L = 50 Ω, C _L = 5.0 pF			-110		
BW	On-Channel -3.0 db Bandwidth	Signal = 0 dB R _L = 50 Ω, C _L = 5.0 pF	1.8 to 5.0		40		MHz
THD	Total Harmonic Distortion	V _{COM} = 2.0 Vp-p, R _L = 600 Ω, T _A = 25°C	-		0.02		%
C _{NO_[OFF]} C _{NC_[OFF]}	NO_, NC_ OFF-Capacitance	F = 10 MHz	-		30		pF
C _{NO_[ON]} C _{NC_[ON]}	NO_, NC_ ON-Capacitance	F = 10 MHz	-		110		pF

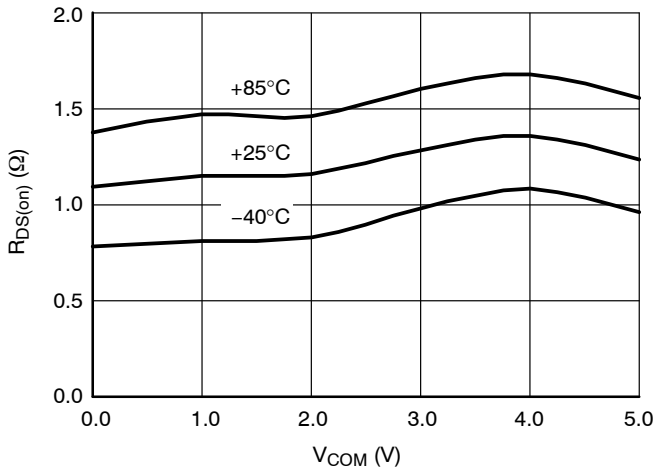


Figure 2. Low $R_{DS(on)}$ @ $V_{CC} = 5.0$ V

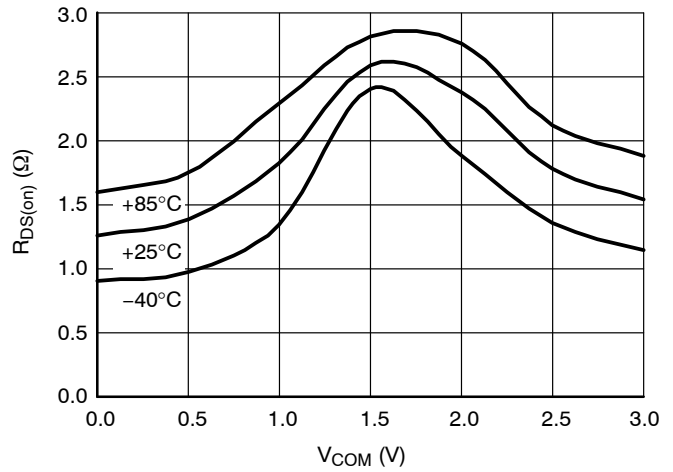


Figure 3. Low $R_{DS(on)}$ @ $V_{CC} = 3.0$ V

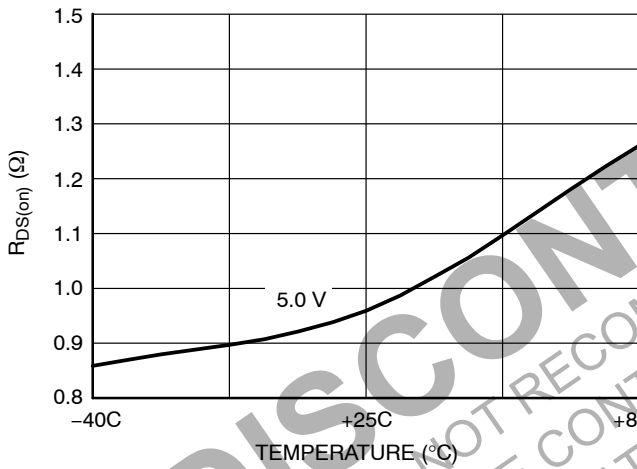


Figure 4. Delta $R_{DS(on)}$ @ $V_{CC} = 5.0$ V

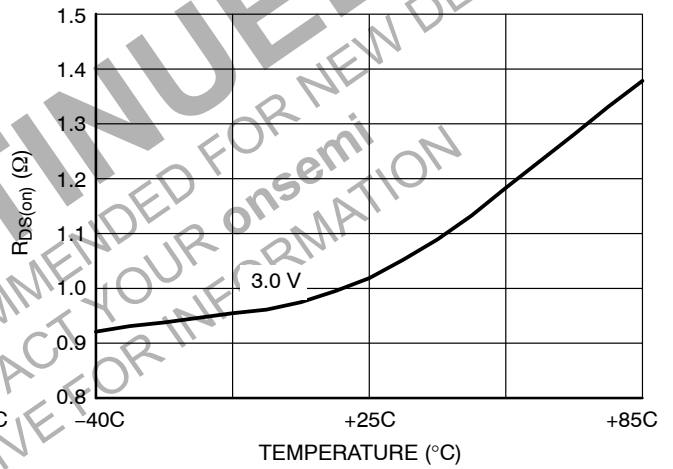


Figure 5. Delta $R_{DS(on)}$ @ $V_{CC} = 3.0$ V

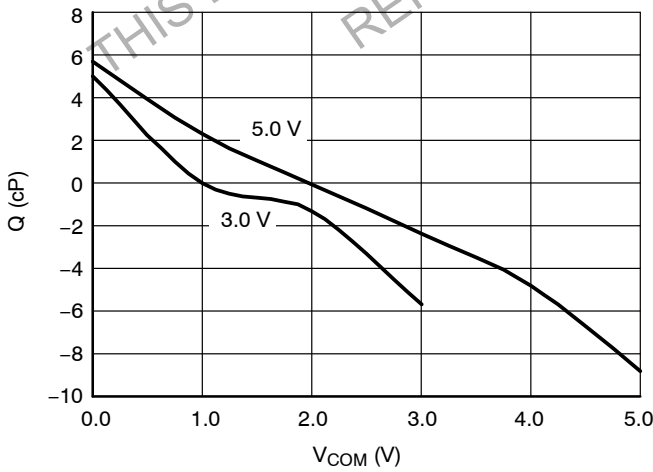


Figure 6. Charge Injection

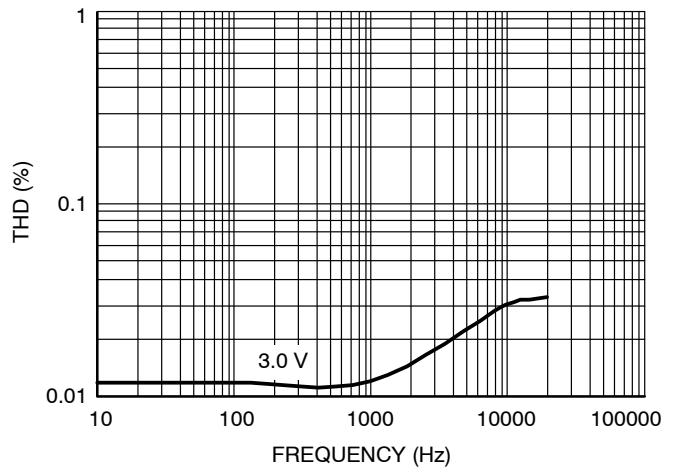


Figure 7. Total Harmonic Distortion

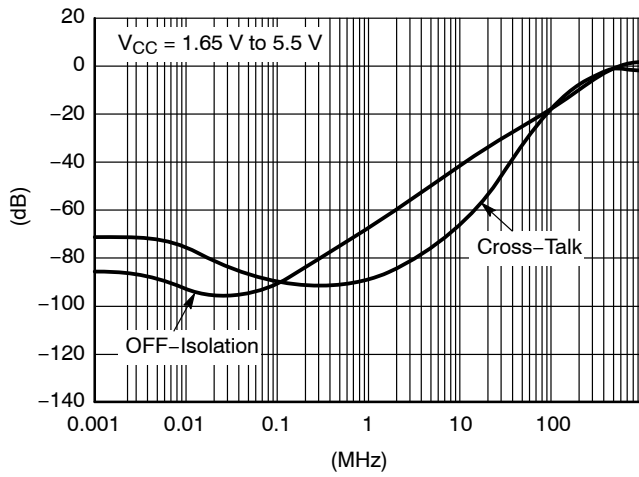


Figure 8. Frequency Response

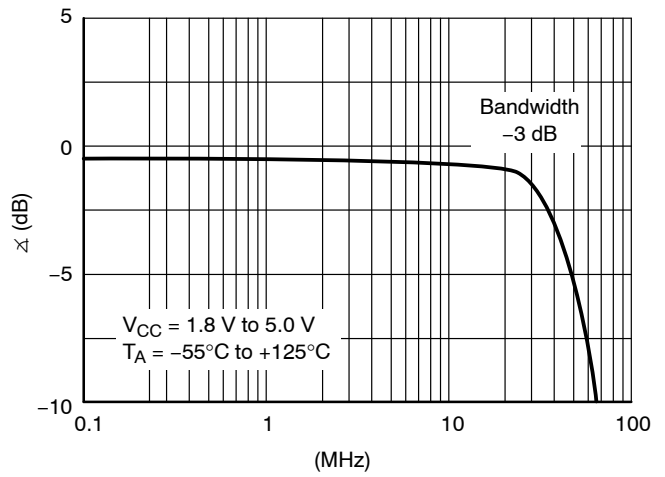


Figure 9. Bandwidth and Phase

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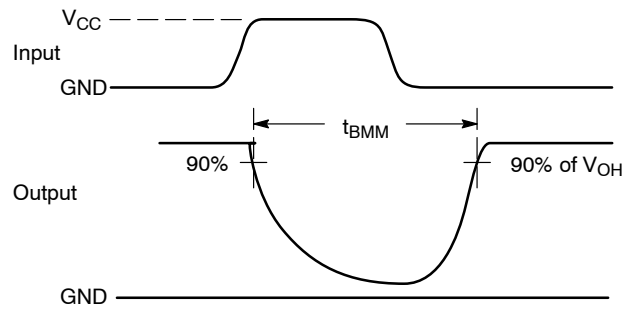
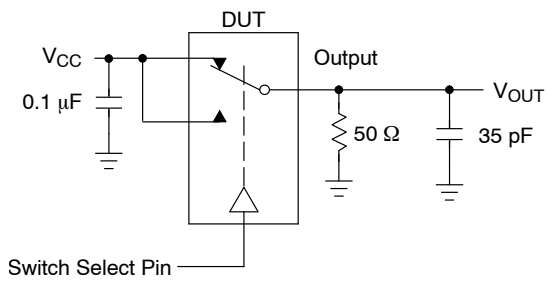


Figure 10. t_{BMM} (Time Break-Before-Make)

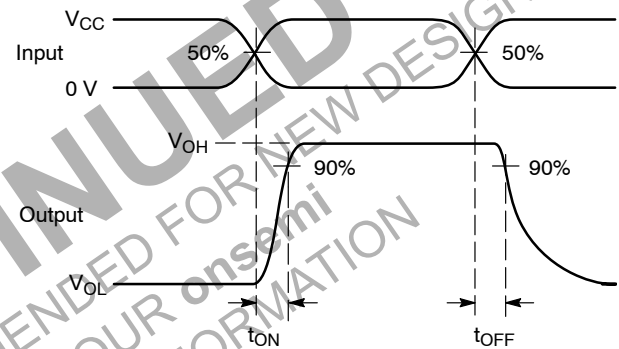
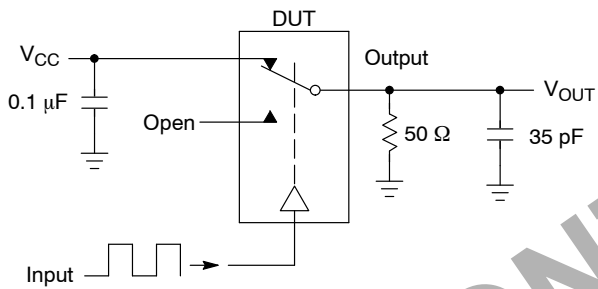


Figure 11. t_{ON}/t_{OFF}

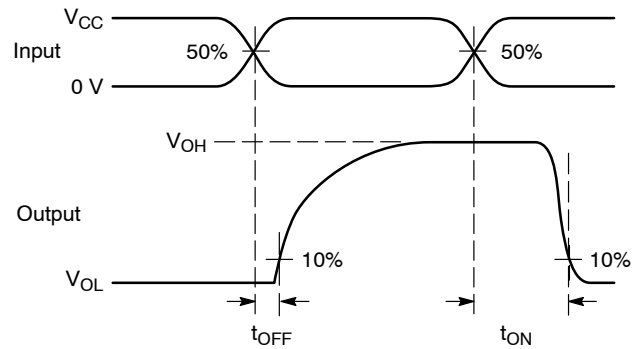
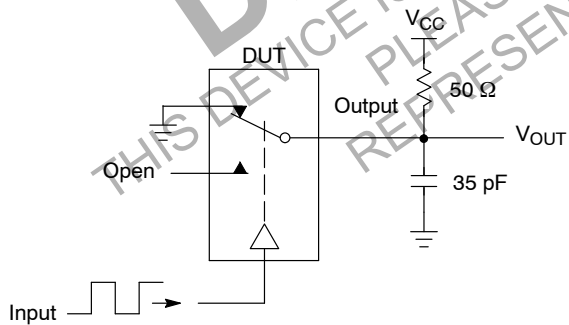
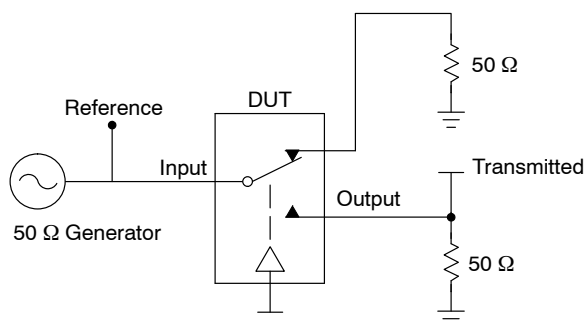


Figure 12. t_{ON}/t_{OFF}



Channel switch control/s test socket is normalized. Off isolation is measured across an off channel. On loss is the bandwidth of an On switch. V_{ISO} , Bandwidth and V_{ONL} are independent of the input signal direction.

$$V_{ISO} = \text{Off Channel Isolation} = 20 \log \left(\frac{V_{OUT}}{V_{IN}} \right) \text{ for } V_{IN} \text{ at } 100 \text{ kHz}$$

$$V_{ONL} = \text{On Channel Loss} = 20 \log \left(\frac{V_{OUT}}{V_{IN}} \right) \text{ for } V_{IN} \text{ at } 100 \text{ kHz to } 50 \text{ MHz}$$

Bandwidth (BW) = the frequency 3.0 dB below V_{ONL}

V_{CT} = Use V_{ISO} setup and test to all other switch analog input/outputs terminated with 50 Ω

Figure 13. Off Channel Isolation/On Channel Loss (BW)/Crosstalk (On Channel to Off Channel)/ V_{ONL}

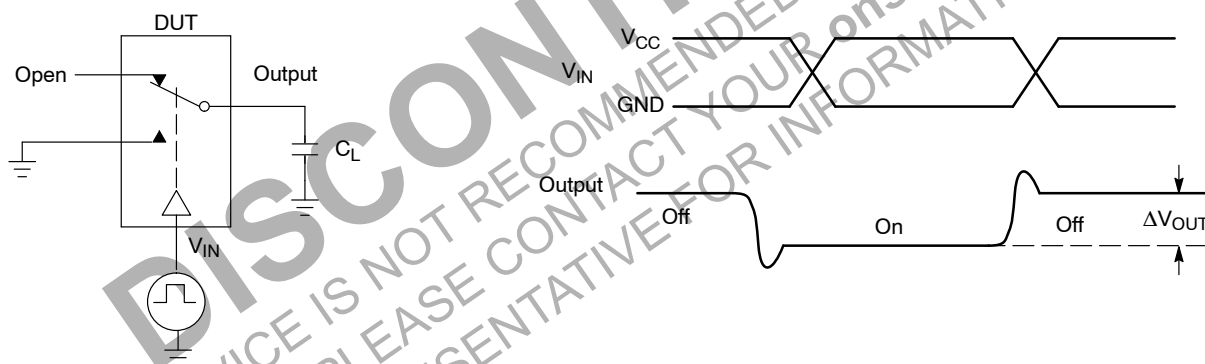
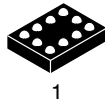


Figure 14. Charge Injection: (Q)

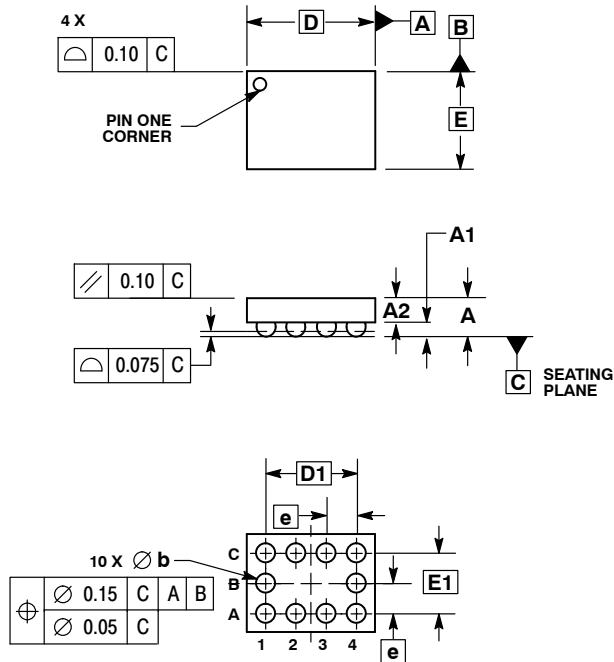
10 PIN FLIP-CHIP
CASE 489AA
ISSUE A

DATE 04 MAY 2004



1

SCALE 4:1

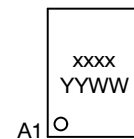


NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. COPLANARITY APPLIES TO SPHERICAL CROWNS OF SOLDER BALLS.

DIM	MILLIMETERS	
	MIN	MAX
A	---	0.650
A1	0.210	0.270
A2	0.280	0.380
D	1.965 BSC	
E	1.465 BSC	
b	0.250	0.350
e	0.500 BSC	
D1	1.500 BSC	
E1	1.000 BSC	

GENERIC
MARKING DIAGRAM*

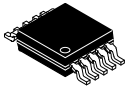


xxxx = Specific Device Code
YY = Year
WW = Work Week

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present.

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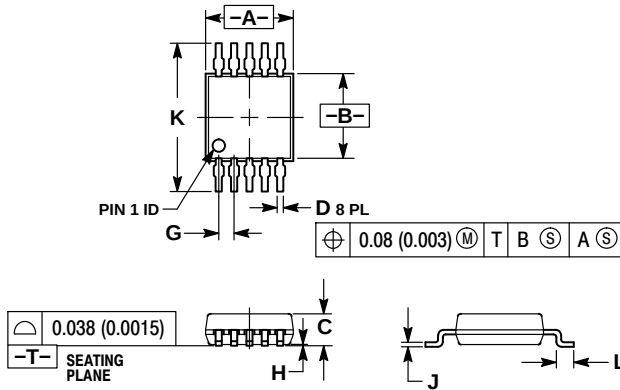
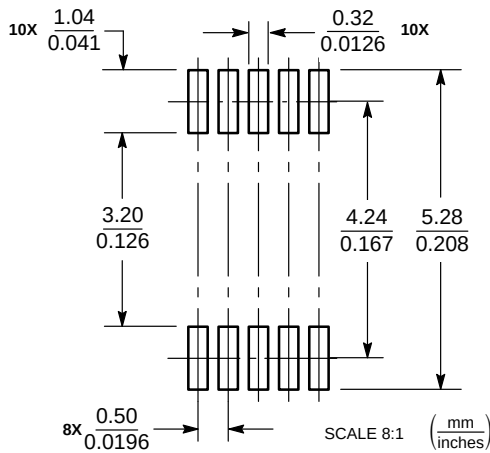
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SCALE 2:1

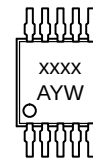
Micro10
CASE 846B
ISSUE D

DATE 07 DEC 2004


SOLDERING FOOTPRINT

Micro10
NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSION "A" DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH, PROTRUSIONS OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
4. DIMENSION "B" DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.
5. 846B-01 OBSOLETE. NEW STANDARD 846B-02

	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
A	2.90	3.10	0.114	0.122
B	2.90	3.10	0.114	0.122
C	0.95	1.10	0.037	0.043
D	0.20	0.30	0.008	0.012
G	0.50 BSC		0.020 BSC	
H	0.05	0.15	0.002	0.006
J	0.10	0.21	0.004	0.008
K	4.75	5.05	0.187	0.199
L	0.40	0.70	0.016	0.028

GENERIC MARKING DIAGRAM*


- xxxx = Device Code
- A = Assembly Location
- Y = Year
- W = Work Week
- = Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "■", may or may not be present. Some products may not follow the Generic Marking.

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